NSN 5961-01-332-8498

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Inclosure Material:

Plastic

Overall Length:

Between 0.069 inches and 0.075 inches

Overall Height:

Between 0.030 inches and 0.040 inches

Overall Width:

Between 0.038 inches and 0.042 inches

Internal Configuration:

Field effect

Mounting Method:

Compression

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

30.0 drain to gate voltage and 30.0 drain to source voltage

Current Rating Per Characteristic:

10.00 milliamperes gate current

Power Rating Per Characteristic:

300.0 milliwatts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Precious Material And Location:

Terminal surfaces and internal wire gold

Precious Material:

Gold

Terminal Type And Quantity:

4 bonding pad

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0